

JC979 U.S. PTO  
10/043194  
10/14/02

PATENT NUMBER and  
ISSUE DATE

U.S. UTILITY Patent Application

APPL NUM	FILING DATE	CLASS	SUBCLASS	GAU	EXAMINER
10043194	01/14/2002	267		2811	

\*\*APPLICANT(S): Jang Wen Yueh

\*\*CONTINUING DATA VERIFIED: *pvw ITT*

\*\* FOREIGN APPLICATIONS VERIFIED: *WU ITT*

PG-PUB	DO NOT PUBLISH <input type="checkbox"/>	RESCIND <input type="checkbox"/>	ATTORNEY DOCKET NO
Foreign priority claimed US USD 113 conditions met Verified by <i>[Signature]</i> - Acknowledged by Examiner's initials		4005-145	

TITLE : Structure of a deep trench-type DRAM and method for making the same

NOTICE OF ALLOWANCE MAILED		Assistant Examiner	CLAIMS ALLOWED	
			Total Claims	Print Claim for O.G
ISSUE FEE		DRAWING		
Amount Due	Date Paid	Sheets Drwg.	Figs.Drwg.	Print Fig.
TERMINAL DISCLAIMER		Primary Examiner		
		PREPARED FOR ISSUE		
		Application Examiner		
WARNING: The information disclosed herein may be restricted. Unauthorized disclosure may be prohibited by the United States Code Title 35, Sections 122, 181 and 368. Possession outside the U.S. Patent & Trademark Office is restricted to authorized employees and contractors only.				

FILED WITH:  DISK (CRF)  CD-ROM  
(Attached in pocket on right inside flap)